NSN 5961-01-356-4290

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-4290 **Inclosure Material:** Ceramic **Overall Length:** Between 0.205 inches and 0.225 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 breakdown voltage, instantaneous **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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